## IEDMS 2021 獲獎名單

Symposium A

	最佳論文獎 Best Paper Award			
Paper ID	Paper Title	Author		
#1130	Impacts of Asymmetric Gate Metal Structure on the Current Behavior of Normally-OFF p-GaN/AlGaN/GaN HEMTs	Tz-Yan Huang, Ya Chun Chang, Chih-Chao Hsu, and Chao-Hsin Wu		
# 1006	High Power High Speed 940 nm Tunnel Junction Flip-Chip VCSEL for LiDAR	Zhi Kuang Lu, Yu Ming Huang, Hao-chung Kuo, and Min-Hsiung Shih		
# 1175	Gelatin for Used in Self-Healing Resistive Memory Device	Jia-Cheng Jian, Yu-Chi Chang, Shoou Jinn Chang, and Sheng-Po Chang		
# 1148	Switching Behaviors of GaN-on-Si Power HEMTs with Deep Source Metal Trenches	Chih-Kang Chang, Dai-Jie Lin, Jhih-Yuan Yang, Yuh-Renn Wu, and Jian Jang Huang		
	佳作論文獎 Excellent Paper Award			
Paper ID	Paper Title	Author		
#1213	300 V – 7.5A Enhancement-Mode p-GaN HEMTs on Silicon Substrate with 100mm Gate Width	Ya-Han Yang, Tong-Wen Wang, and Meng-Chyi Wu		
#1026	AlGaN/AlN/GaN Metal-Oxide-Semiconductor High Electron Mobility Transistors with Ni/Au Gate Electrode	Jung-Hui Tsai, Jing-Shiuan Niu, Li-An Tsai, Wei-Che Shao, and Wen-Chau Liu		
#1037	A Novel Heterostructure Schottky Diode with a Bimetallic Surface Structure for Hydrogen Sensing Application	Wei-Cheng Chen, Jing-Shiuan Niu, Pu-Yuan Ke, Shiou-Ying Cheng, and Wen-Chau Liu		
#1271	Investigation of TiO2/AlGaN/GaN Metal-Oxide- Semiconductor High-Electron Mobility Transistors	Yu-Shyan Lin, Chi-Che Lu, and Wei-Chou Hsu		
#1093	Al2O3-Dielectric AlGaN/AlN/SiC Widegap Channel MOS-HFETs	Ching Sung Lee, Yun Zhong Lin, Yan TIing Shen, Jian Hong Ke, Zhi Zong Zheng, Yu Xuan Li, Jia Sheng Chen, Zheng Yang You, and Wei-Chou Hsu		
#1251	Comparison of ultraviolet sensing performance of IGZO thin film transistors with Schottky metal and p-type NiO capping layer	Sin-Jhih Huang, Meng-Yung Su, Rong-Ming Ko, Chao-Yen Chang, Chien-Hung Wu, and Shui-Jinn Wang		
	最佳海報論文獎 Best Pos	ter Paper Award		
Paper ID	Paper Title	Author		
#1025	Nanocomposite of tin oxide and tungsten oxide for ethanol gas sensor	Feng-Renn Juang		
#1260	Oxygen-based digital etch for arsenic-based III-V materials and the fabrication of InGaAs MOSFET	Yu Chen, Yan-Kui Liang, and Chun Hsiung Lin		
#1038	Formaldehyde gas sensing properties of a sputtered vanadium pentoxide thin film decorated with gold nanoparticles	Jing-Shiuan Niu, Yen-Lin Pan, and Wen-Chau Liu		
	佳作海報論文獎 Excellent P	oster Paper Award		
Paper ID	Paper Title	Author		
#1048	Gate Breakdown Analysis of Schottky p-GaN gate HEMTs under High Positive Gate Bias	Zhen-Wei Qin, Wei-Chia Chen, Hao-Hsuan Lo, and Yue-ming Hsin		
#1203	Investigation of Recessed-Gate InAIN/GaN High Electron Mobility Transistors	Chong-Jie Huang, Cheng-Yang You, Ba Kuan- Jen, Yi-Ping Huang, Wei-Chou Hsu, and Ching- Sung Lee		
#1214	The Study of Electrical Properties and Photoresponsivity of BiFeO3 Crossbar Resistive Random Access Memory	Yu-Chi Chang, Chung Chieh Shih, and Ricky Wenkuei Chuang		
	· •			

#1034	Enhanced Performance of SnO2-based Thin-Film Transistors by Barium Doping	Han-Yin Liu, and Yu-Jie Liao
#1077	An ITO-based High Surface Area Hydrogen Sensor with Fast Predictive Ability	Kun Wei Lin, and Cheng Hao Wu
#1164	IC haracteristics of AllinN/GaN HEMILs on Different	Yu-Cheng Chang, Yu Jie Luo, Wei Cheng Tzeng, Tz-Yan Huang, and Chao-Hsin Wu
#1139	Pt/AlGaN/GaN High Electron Mobility Transistors for High- Sensitivity Hydrogen Sensor Applications	Yin-Yu Hsueh, Po-Cheng Pan, Pu-Chou Lin, and Yeong-Her Wang

Symposium B

Sympo	Symposium B		
	最佳論文獎 Best Pa	per Award	
Paper ID	Paper Title	Author	
#1008	Performance Improvement of Amorphous InGaZnO Thin Film Transistors Using Double-layer Structure	Jih-Chao Chiu, Song-Ling Li, Ming-Xuan Lee, and Chee-Wee Liu	
# 1182	Enhanced Self-stability of Un-capsulated Polycrystalline MAPbI3 Solar Cells with Urea and Fullerene additives	Diksha Thakur, Shou En Chiang, Jyh-Shyang Wang, and Sheng Hsiung Chang	
# 1206	Studies of Transport Properties and Scaling Issues of MoS2 and WS2 Based Transistors	Pin-Fang Chen ,Che-Yu Wu , and Yuh-Renn Wu	
	佳作論文獎 Excellent	Paper Award	
Paper ID	Paper Title	Author	
#1273	The First Demonstration of the Optoelectrical Amplifier and High Resolution Thermal Sensor with Light-Emitting Transistors	Lu-Ching Hsueh, Sheng-Wen Cheng, Hsin-Yu Lin, Mukul Kumar, and Chao-Hsin Wu	
#1170	Charge Storage of Isolated Mono-layer Molybdenum Disulfide in Epitaxially Grown MoS2/Graphene Hetero-structures	Po-Cheng Tsai, Chun Wei Huang, Shoou Jinn Chang, Shu-Wei Chang, and Shih-Yen Lin	
# 1234	Quantization Effect on the Magnetotransport in Textured Bi(0003) Nanofilms	Lee Chi Hung, Chieh Chou, Chao-Chuan Chen, and Hao-Hsiung Lin	
# 1030	Titanium-Doped Cerium Fluoride Sensing Membrane Applied in Extend Gate Field Effect Transistor Devices	Yen Su, Chyuan Haur Kao, Yun-Hao Lin, Chan Yu Lin, Yu Ching Liao, Munmun Das, Titisha Chakraborty, Min Zhe Wei	
# 1133	High-Performance Solution-Processed Cu2O Photodetector Arrays via UV- Irradiation	Hung Chen, Sheng-Wei Pai, Ming-Hsien Li, and Chun-Ying Huang	
	最佳海報論文獎 Best Pos	ter Paper Award	
Paper ID	Paper Title	Author	
#1101	Investigation of Hybrid MgZnO Nanoparticles Chitosan Non-Volatile Resistive Memory Devices with Different Mg Composition	I-Ching Tsai, Wei-Chiao Liao, Chih-Chia Su, Wang Zi-Hao, and Hsin-Chieh Yu	
#1173	HfZrO2 Ferroelectric Thin-Film Transistors Based on InGaZnO Channels for Memory Applications	Chun-Wei Chang, Yu-Hsin Kuo, Chun-Yu Liao, Min-Hung Lee, and I-Chun Cheng	
	佳作海報論文獎 Excellent P	oster Paper Award	
Paper ID	Paper Title	Author	
#1272	Effective Reduction of Defects at the Ge0.96Sn0.04/Al2O3 Interface by Rapid Thermal Oxidation and Oxygen Plasma	Yi-Chieh Chen, Chia-You Liu, Yu-Rui Wu, Cheng-Kai Hsiung, and Jiun-Yun Li	
#1137	Stacked Three-dimensional Crossbar Resistive Random Access Memory based Synapse for Neuromorphic Computing	Szu-Han Hu, Min-Jung Tsai, Fang-Rong Zhang, Ke-Jing Lee, Dar-Sen Lu, Ting- Chang Chang, and Yeong-Her Wang	

#1082	Fabrication of Two-Dimensional Tungsten Disulfide Thin Film	Sheng-Po Chang, Guan-Yuan Liou, Chieh-Yu Kuan, Qi Rui Qiu, Wei-Lun Huang, Jone F. Chen, Shoou Jinn Chang, and Wei-Chih Lai
#1156	Perovskite Quantum Dots/Silicon White Light	Chao-Yu Tiao, Yi-Shan Shih, Jun-Hao Shen, and
	Photodetectors	Wei-Chen Tu
#1199	Effects of Metallic Dopants in Indium Oxide-based Thin-Film Transistor for Monolithic Three- Dimension Integrated Circuits	Yu-Chen Chen, Zhen-Hao Li, Tsung-Che Chiang, Chun-Hao Tu, and Po-Tsun Liu
#1136	Ultrahigh Spin-Transfer Torque Effect in Superlattice-Barrier Magnetic Tunnel Junctions Using Half-Metallic Magnets	Chun-Pu Wang, Shih-Hung Cheng, Jing-Ci Su, Sin-You Huang, Yu-Chi Chen, Peng Tseng, and Wen-Jeng Hsueh

J I	Symposium C 最佳論文獎 Best Paper Award		
Paper ID	来 住端 久突 Best Tal	Author	
	Dependency of Transient Current Behavior on Oxide		
#1032	Thickness in Trench Structure MIS TDs	Jian-Yu Lin and Jenn-Gwo Hwu	
	Germanium Quantum Dots Arrays with Self-	LILE WAS DENC WANC DINC CHINCLIN	
#1094	organized Confinement Barriers and Self-aligned	I Hsiang Wang, PENG KANG-PING, CHING LUN CHEN, Horng-Chih Lin, and Pei-Wen Li	
	Electrodes for Quantum-Computing Devices	CHEN, Horng-Chin Lin, and Fel-Wen Li	
	佳作論文獎 Excellent	Paper Award	
Paper ID	Paper Title	Author	
	New Observations on Strain-enhanced Cryogenic		
#1107	Ballistic Transport in Advanced FinFETs for High-	E-Ray Hsieh	
	performance Cold-electronic Applications		
#1018	Physical Unclonable Function by Random Plasma	Wei Chang ,Chrong Jung Lin, and Ya-Chin King	
#1018	Charging Event in FinFET CMOS Processes	Wel Chang, Chrong Jung Lin, and Ta-Chin King	
#1150	TCAD Based Study of the Impact of Traps on RF	Jhao-Lin Huang, Yu-Che Liu, and Meng-Hsueh	
π1130	FinFETs	Chiang	
	Theorical Analysis of Reverse Current of MIS(p)	kung-chu Chen, Kuan-Wun Lin, and Jenn-Gwo	
#1015	Tunnel Diodes with Oxide Thickness in Ultra-thin	Hwu	
	Region	11wu	
	最佳海報論文獎 Best Pos	ter Paper Award	
Paper ID	Paper Title	Author	
	Investigation on Hot-carrier Induced Degradation	Chao-Hung Wang, Jone F. Chen, Po-Hao Ko, Jin-	
#1102	and Lifetime of HVMOSFETs	Chin Liao, Ke-Jhu Pan, Yun-Chien Tsai, and	
	and Electine of IT viviosi E13	Sheng-Po Chang	
	Interface Engineering of High-κ Dielectric for Ge MOSFETs	Chiung-Yi Yang, Hsin-Fu Huang, Tzu-Chieh	
#1180		Hong, Yao-Jen Lee, Chun-Jung Su, Wen-Fa Wu,	
		Tien-Sheng Chao, and Yeong-Her Wang	
	佳作海報論文獎 Excellent F	Poster Paper Award	
Paper ID	Paper Title	Author	
#1202	An Optimized Ferroelectric Option to Nanosheet	Narasimhulu Thoti and Yiming Li	
π1202			
	Vertical Tunneling FETs	That and Thing Er	
	Scalability Assessment of Ferroelectric-FET NVMs		
	Scalability Assessment of Ferroelectric-FET NVMs considering Ferroelectric Phase Nonuniformity	Yuan Yu Huang, You-Sheng Liu, and Pin Su	
	Scalability Assessment of Ferroelectric-FET NVMs considering Ferroelectric Phase Nonuniformity using Voronoi Approach		
	Scalability Assessment of Ferroelectric-FET NVMs considering Ferroelectric Phase Nonuniformity using Voronoi Approach Metal Contamination Suppression on Nickel-	Yuan Yu Huang, You-Sheng Liu, and Pin Su	
#1097	Scalability Assessment of Ferroelectric-FET NVMs considering Ferroelectric Phase Nonuniformity using Voronoi Approach  Metal Contamination Suppression on Nickel-induced Laterally Crystallized Low-Temperature	Yuan Yu Huang, You-Sheng Liu, and Pin Su Yu-Ting Tsai, Zhen-Hao Li, Tsung-Che Chiang,	
	Scalability Assessment of Ferroelectric-FET NVMs considering Ferroelectric Phase Nonuniformity using Voronoi Approach  Metal Contamination Suppression on Nickel-induced Laterally Crystallized Low-Temperature Polycrystalline Silicon Thin-Film Transistors for	Yuan Yu Huang, You-Sheng Liu, and Pin Su	
#1097	Scalability Assessment of Ferroelectric-FET NVMs considering Ferroelectric Phase Nonuniformity using Voronoi Approach  Metal Contamination Suppression on Nickel-induced Laterally Crystallized Low-Temperature Polycrystalline Silicon Thin-Film Transistors for Monolithic 3D-IC Applications	Yuan Yu Huang, You-Sheng Liu, and Pin Su Yu-Ting Tsai, Zhen-Hao Li, Tsung-Che Chiang, Shao Chi Lo, Po-Yi Kuo, and Po-Tsun Liu	
#1097	Scalability Assessment of Ferroelectric-FET NVMs considering Ferroelectric Phase Nonuniformity using Voronoi Approach  Metal Contamination Suppression on Nickel-induced Laterally Crystallized Low-Temperature Polycrystalline Silicon Thin-Film Transistors for	Yuan Yu Huang, You-Sheng Liu, and Pin Su Yu-Ting Tsai, Zhen-Hao Li, Tsung-Che Chiang,	

#1239	Evaluation of FE behavior in Pt/TiN/HZO/p-Si	Asim Senapati, SIDDHESWAR MAIKAP,
	MFS and Pt/TiN/HZO/TiN MFM structure for	Abhijit Aich, Chen Ying Lin, Chun-Yu Liao, and
	future logic/memory devices	Min-Hung Lee
#1031	Impact of Inner Spacer on Gate-Induced Drain	Jia Ying Lin, YU GAN WANG, Chia An Wang,
	Leakage Current in Nanosheet FET	and Meng-Hsueh Chiang
#1217	Silicon Wafer Surface Treatment Process for Solar	Yu-Chun Huang, Ricky Wenkuei Chuang, Y D
	Photovoltaics	Wu, Wei-Chen Tien, and Man-Ying Wang
#1286	Nanosheet Compatible Complementary FET Logic	
	Non Volatile Memory Device for 3nm CMOS and	Darsen Lu, Yu-Ming Chang, and Yao-Jen Lee
	Beyond	

Sympo	Symposium D		
	最佳論文獎 Best Pa	per Award	
Paper ID	Paper Title	Author	
#1159	Dispersion Relation and Condensation of Exciton— Polaritons in ZnO Whispering-Gallery Microcavities	Sheng-Chan Wu, Gia-Yuan Zhuang, Chung-Xian Yang, Yia-Chung Chang, and Hsu-Cheng Hsu	
#1258	Gate-Stacking Heterostructure Design and Fabrication of Self-aligned ITO/Ge dots/SiO2/SiGe photoMOSFETs for Si-based Optical Interconnects	Po-Yu Hong, Bing Ru Li, Horng-Chih Lin, and Pei- Wen Li	
	佳作論文獎 Excellent	Paper Award	
Paper ID	Paper Title	Author	
#1098	AC-Driven Multi-Color Electroluminescent from a Hybrid WSe2/AlGaInP Light-Emitting Device	Ya-Hui Chang, Yen-Shou Lin, Hsiang-Ting Lin, Hao-Chung Kuo,and Min-Hsiung Shih	
#1114	On-Wafer DUV Detector Through Metal Sensing Pad by 28nm CMOS Technologies	Chia-Ru Lu, Chien-Ping Wang, Jiaw-Ren Shih, Chrong Jung Lin, and Ya-Chin King	
#1055	Aluminum-Gallium-Oxide based Ultraviolet Photodetector	Sheng-Po Chang, Shen-Hao Zhang, Chih-Yung Wang, Wei-Lun Huang, Yi-Hsin Liu, Wei-Chih Lai, and Shoou Jinn Chang	
#1189	Defect and inter-sphere coupling effects on high-Q modes in ZnO microspheres	Ching-Hang Chien, Chia-Liang Liu, and Yia- Chung Chang	
#1033	Gallium Nitride Metalenses at Visible Wavelengths	Chen Meng-Hsin, Li Jia-Ying, Su Vin-Cent, Hsiung Chieh Kuan, and Lin Hoang Yan	
	最佳海報論文獎 Best Pos	ter Paper Award	
Paper ID	Paper Title	Author	
#1124	On the study of GPS band pass protectors with Si based AlGaN/GaN symmetric varator	CHNG-HAO YANG, Liann-Be Chang, MING- JER JENG, Yu-Li Hsieh, Chia-Ning Chang, and Zi-Xin Ding	
#1142	Stability Improvement of Low-bandgap Perovskite Solar Cell Using Formamidinium as Cation	Yu-Han Hung, CHENLUN LAN, Wei-Chou Hsu, and En-Ping Yao	
	佳作海報論文獎 Excellent P	oster Paper Award	
Paper ID	Paper Title	Author	
#1123	Comparison Study of SiN and TiO2 Sandwiched Colloidal Quantum-Dot Microdisks	Kai-Wen Chen and Ming-Hua Mao	
#1128	Fabrication and Properties of InWO Ultraviolet Photodetector	Sheng-Po Chang, Chieh-Yu Kuan, Po-Ju Wu, Wei-Lun Huang, Qi Rui Qiu,Wei-Chih Lai, and Shoou Jinn Chang	
#1190	Photon-current Conversion from High-level Singlet Fission Reaction in Tetracene-based Diodes	Shi Hong Luo, Wu Chien-Chih, and Tzung-Fang Guo	

#1196	Enhance Power Conversion Efficiency of Non-toxic Rudorfittes Solar Cells through Modification of Carrier Transporting Layer	Yu-Hsiang Chang, Yu Yen-Fu, kai-chi Hsiao, Shih-Hsuan Chen, and Ming-Chung Wu
#1292	Round States in the Continuum	Yi-Chen Wang, Bo-Xiang Cao, Tsung-Bo Chen, Chi-Ting Weng, Zhang-Qi Liao, Yu-Chen Hsu, and Jui-Nung Liu